# DATA SHEET

OCMOS FET PS7160-1A,PS7160L-1A

**Solid State Relay** 

## 6-PIN DIP, 600 V BREAK DOWN VOLTAGE 1-ch Optical Coupled MOS FET

#### DESCRIPTION

NEC

The PS7160-1A and PS7160L-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7160L-1A has a surface mount type lead.

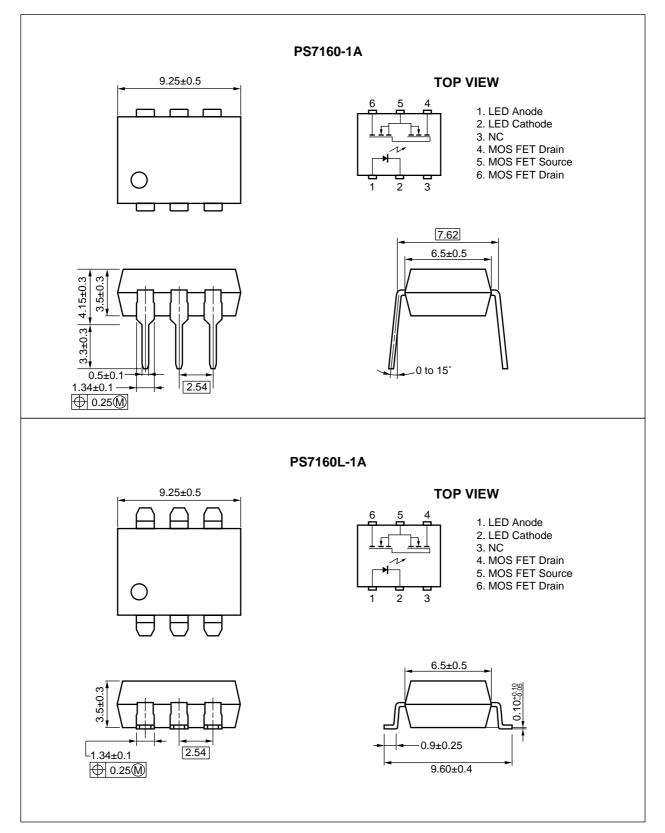
#### **\*** FEATURES

- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS7160L-1A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- CSA approved: No. CA 101391

#### APPLICATIONS

- Exchange equipment
- Measurement equipment
- FA/OA equipment

## PACKAGE DIMENSIONS (in millimeters)



### **\*** ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7160-1A	6-pin DIP	Magazine case 50 pcs	PS7160-1A
PS7160L-1A			PS7160L-1A
PS7160L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7160L-1A-E4			

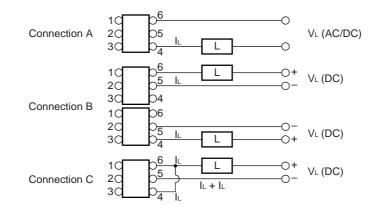
\*1 For the application of the Safety Standard, following part number should be used.

	Parameter			Ratings	Unit
Diode	Forward Current (DC)		lf	50	mA
	Reverse Voltage		VR	5.0	V
	Power Dissipation		PD	50	mW
	Peak Forward Current <sup>*1</sup>		FP	1	А
MOS FET	Break Down Voltage		VL	600	V
	Continuous	Connection A	l.	90	mA
	Load Current <sup>*2</sup>	Connection B		130	
		Connection C		200	
	Pulse Load Current <sup>*3</sup> (AC/DC Connection)		Ilp	250	mA
	Power Dissipation		PD	560	mW
Isolation Vo	Isolation Voltage <sup>*4</sup>		BV	1 500	Vr.m.s.
Total Powe	Total Power Dissipation		Р⊤	610	mW
Operating A	Operating Ambient Temperature		TA	-40 to +80	°C
Storage Te	Storage Temperature		Tstg	-40 to +100	°C

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C, unless otherwise specified)

\*1 PW = 100  $\mu$ s, Duty Cycle = 1 %

\*2 Conditions: IF  $\geq$  2 mA. The following types of load connections are available.



\*3 PW = 100 ms, 1 shot

\*4 AC voltage for 1 minute at  $T_A = 25$  °C, RH = 60 % between input and output

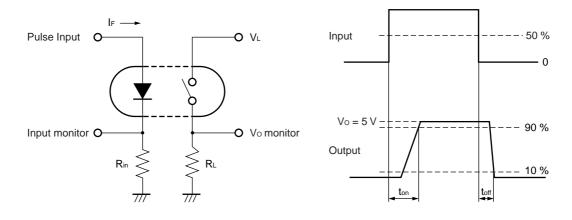
### **RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

## **\*** ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	Ir	V <sub>R</sub> = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	Loff	V <sub>D</sub> = 600 V		0.03	1.0	μA
	Output Capacitance	Cout	V <sub>D</sub> = 0 V, f = 1 MHz		110		pF
Coupled	LED On-state Current	IFon	I∟ = 90 mA			2.0	mA
	On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		42	50	Ω
		Ron2	$I_{\text{F}}$ = 10 mA, $I_{\text{L}}$ = 90 mA, $t \leq$ 10 ms		33	50	
	Turn-on Time <sup>⁺1</sup>	ton	$I_{\text{F}}$ = 10 mA, Vo = 5 V, PW $\geq$ 10 ms		0.8	1.5	ms
	Turn-off Time <sup>™</sup>	toff			0.06	0.2	
	Isolation Resistance	Ri-o	VI-O = 1.0 kVDC	10 <sup>°</sup>			Ω
	Isolation Capacitance	CI-0	V = 0 V, f = 1 MHz		1.1		pF

\*1 Test Circuit for Switching Time



7580

f = 1 MHz

100

I⊧ = 10 mA

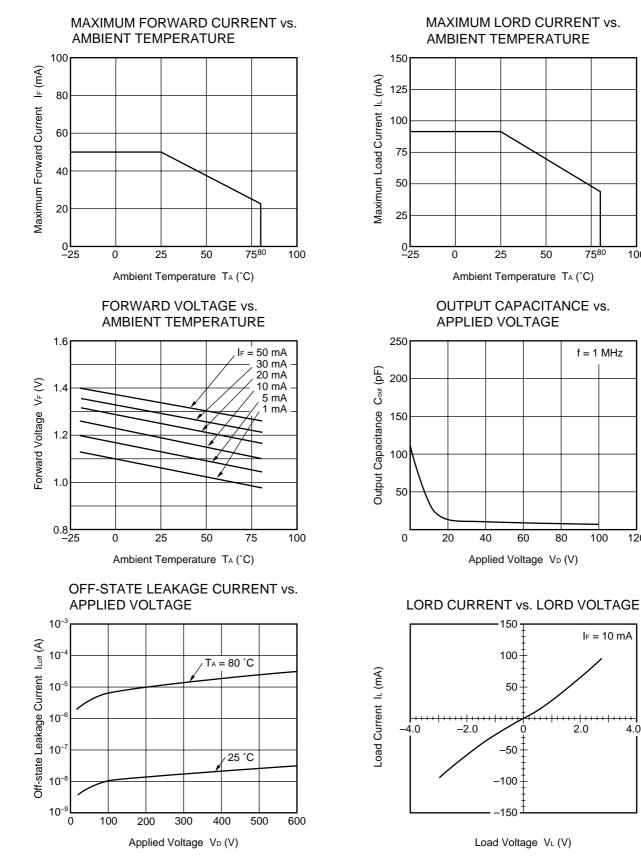
2.0

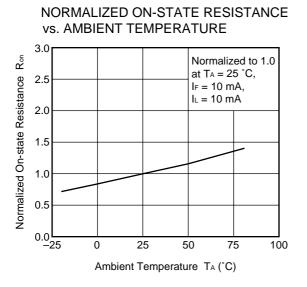
120

4.0

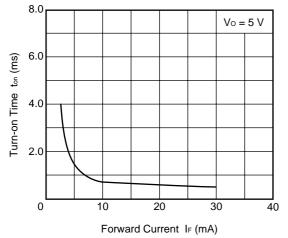
100

#### TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

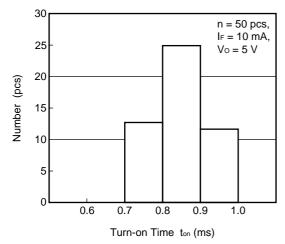




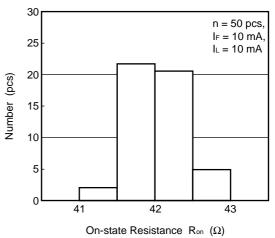




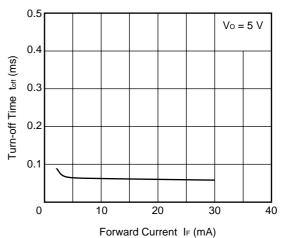
TURN-ON TIME DISTRIBUTION



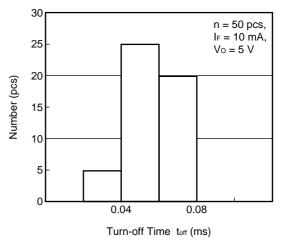
**ON-STATE RESISTANCE DISTRIBUTION** 

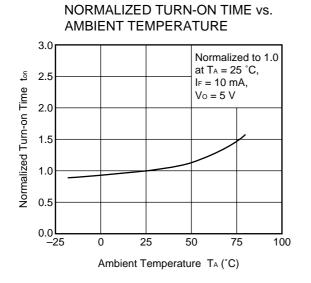


TURN-OFF TIME vs. FORWARD CURRENT

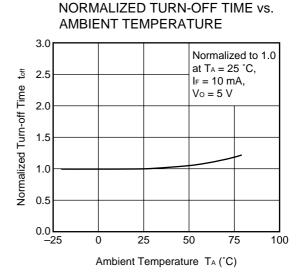


TURN-OFF TIME DISTRIBUTION

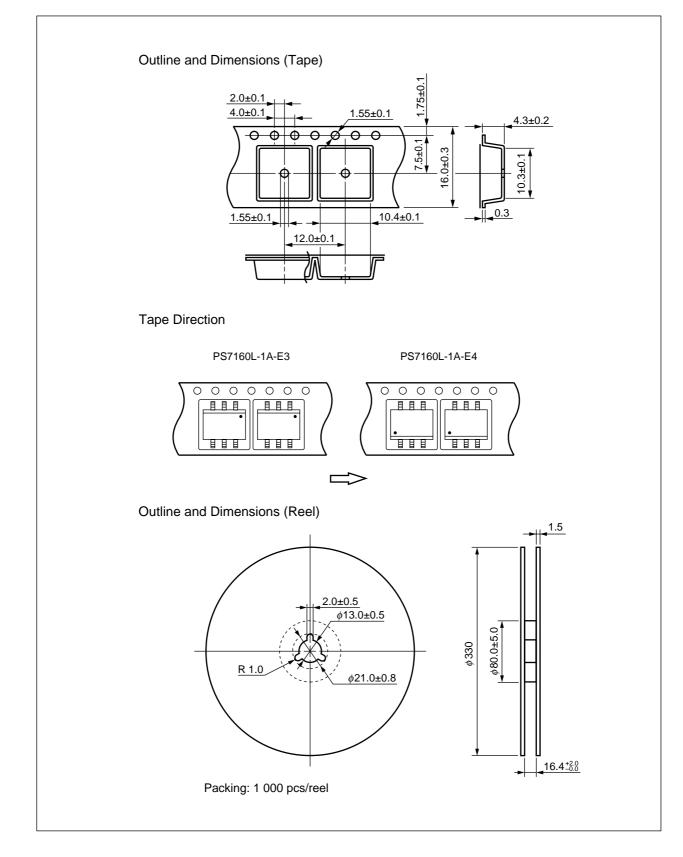




Remark The graphs indicate nominal characteristics.



### **\*** TAPING SPECIFICATIONS (in millimeters)



## **RECOMMENDED SOLDERING CONDITIONS**

## (1) Infrared reflow soldering

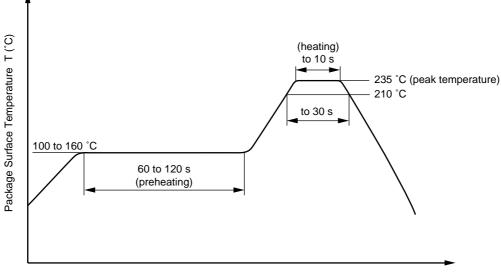
- Peak reflow temperature
  235 °C (package surface temperature)
- Time of temperature higher than 210 °C
- Number of reflows
- Flux

+

30 seconds or less Two

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

#### Recommended Temperature Profile of Infrared Reflow





#### (2) Dip soldering

#### • Temperature 260 °C or below (molten solder temperature)

- Time
  - e 10 seconds or less
- Number of times One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

### (3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

## CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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